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Bib Data Sheet

CONFIRMATION NO. 4282

SERIAL NUMBER 10/720,378	FILING OR 371(c) DATE 11/25/2003 RULE	CLASS 257	GROUP ART UNIT 2814	ATTORNEY DOCKET NO. 492322001810
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** CONTINUING DATA *****

This application is a DIV of 09/925,628 08/10/2001 PAT 6,690,070

** FOREIGN APPLICATIONS *****

JAPAN 2000-242617 08/10/2000 Yes, 8N

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

** 03/11/2004

Foreign Priority claimed	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no
35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> Met after Allowance
Verified and Acknowledged	Examiner's Signature Initials

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TITLE

Method of manufacturing insulated gate semiconductor device

FILING FEE RECEIVED 770	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
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